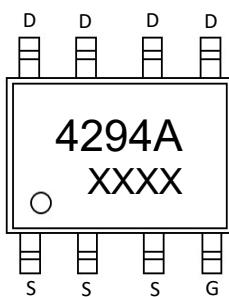


## Features

- Split Gate Trench MOSFET technology
- Low  $R_{DS(on)}$  & FOM
- Excellent stability and uniformity
- Fast switching and soft recovery

## Application

- High Frequency Switching
- Synchronous-rectification



4294A: Device code  
XXXX : Code

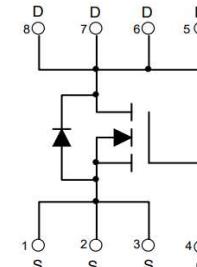
Marking and pin assignment

## Product Summary

$V_{DS}$	$R_{DS(ON)} \text{ MAX}$	$I_D \text{ MAX}$
100V	16mΩ@10V	12A
	25mΩ@4.5V	



SOP-8 top view



Schematic diagram



Halogen-Free

## Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Unit
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## Common Ratings (TC=25°C Unless Otherwise Noted)

$V_{DS}$	Drain-Source Breakdown Voltage	100	V
$V_{GS}$	Gate-Source Voltage	$\pm 20$	V
$T_J$	Maximum Junction Temperature	150	°C
$T_{STG}$	Storage Temperature Range	-50 to 155	°C
$I_S$	Diode Continuous Forward Current	12	A

## Mounted on Large Heat Sink

$I_{DM}$	Pulse Drain Current Tested	Tc=25°C	73	A
$I_D$	Continuous Drain Current	Tc=25°C	12	A
$P_D$	Maximum Power Dissipation	Tc=25°C	6.6	W
$R_{θJA}$	Thermal Resistance Junction-Ambient		75	°C/W

## Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MLSQ4294A	SOP-8	4294A	3,000	6,000	42,000	13"reel

**Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)**

Symbol	Parameter	Condition	Min	Typ	Max	Unit
<b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
BV <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	100	--	--	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =100V, V <sub>GS</sub> =0V	--	--	1	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	--	--	±100	nA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	1.4	1.8	2.4	V
R <sub>DS(on)</sub>	Drain-Source On-State Resistance	V <sub>GS</sub> =10V, I <sub>D</sub> =11.5A	--	12	16	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =9.5A	--	20	25	mΩ
<b>Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
C <sub>ISS</sub>	Input Capacitance	V <sub>DS</sub> =50V, V <sub>GS</sub> =0V, f=1MHz	--	3800	--	pF
C <sub>OSS</sub>	Output Capacitance		--	180	--	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		--	150	--	pF
<b>Switching Characteristics</b>						
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =50V, I <sub>D</sub> =12A, V <sub>GS</sub> =10V	--	90	--	nC
Q <sub>gs</sub>	Gate Source Charge		--	10	--	nC
Q <sub>gd</sub>	Gate Drain Charge		--	24	--	nC
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DS</sub> =50V, I <sub>D</sub> =12A, V <sub>GS</sub> =10V, R <sub>G</sub> =3Ω	--	13	--	nS
t <sub>r</sub>	Turn-on Rise Time		--	14	--	nS
t <sub>d(off)</sub>	Turn-Off Delay Time		--	25	--	nS
t <sub>f</sub>	Turn-Off Fall Time		--	10	--	nS
<b>Source- Drain Diode Characteristics</b>						
V <sub>SD</sub>	Forward on voltage	T <sub>j</sub> =25°C, I <sub>s</sub> =12A	--	--	1.2	V

### Typical Operating Characteristics

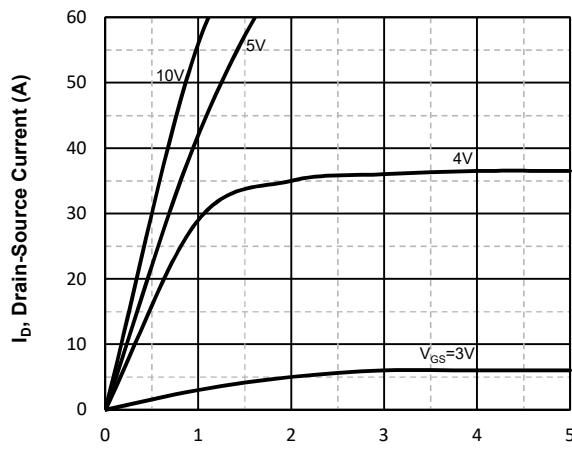


Fig1. Typical Output Characteristics  
 $V_{DS}$ , Drain -Source Voltage (V)

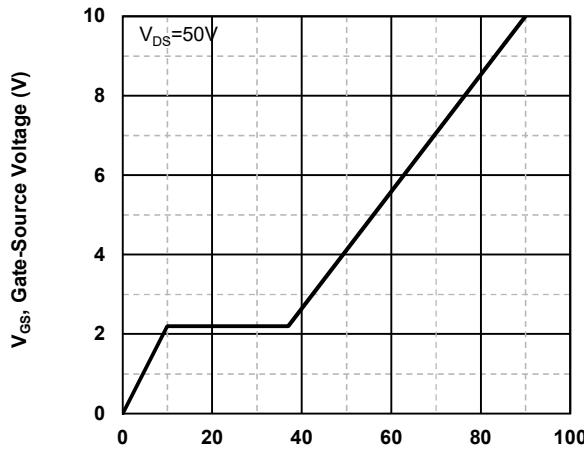


Fig2. Typical Gate Charge Vs.Gate-Source Voltage  
 $V_{DS}=50V$   
 $Q_g$  -Total Gate Charge (nC)

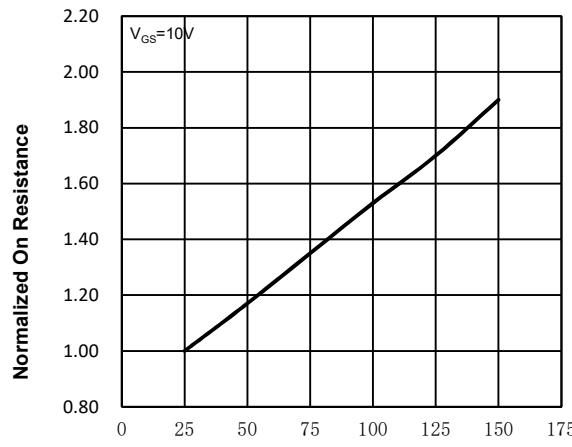


Fig3. Normalized On-Resistance Vs. Temperature  
 $V_{GS}=10V$   
 $T_j$  - Junction Temperature (°C)

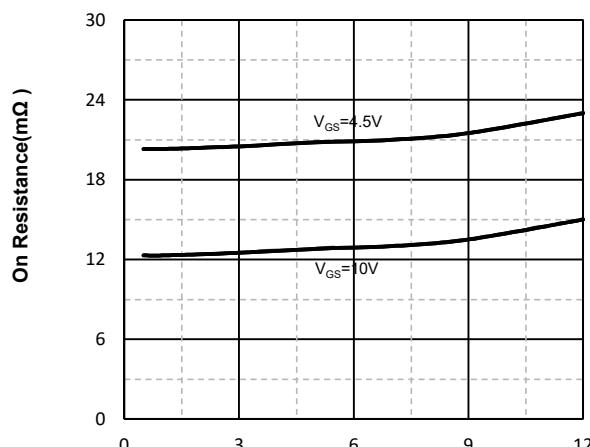


Fig4. On-Resistance Vs. Drain-Source Current (A)  
 $V_{GS}=4.5V$   
 $V_{GS}=10V$

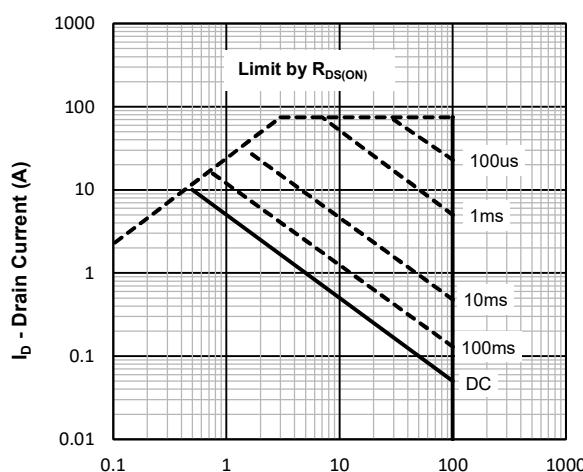


Fig5. Maximum Safe Operating Area  
 $V_{DS}$ , Drain -Source Voltage (V)

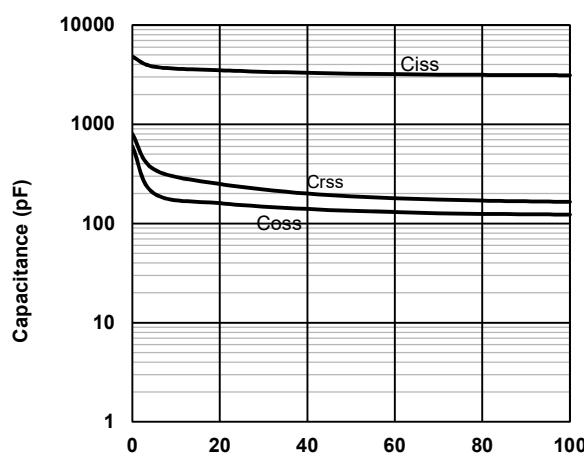
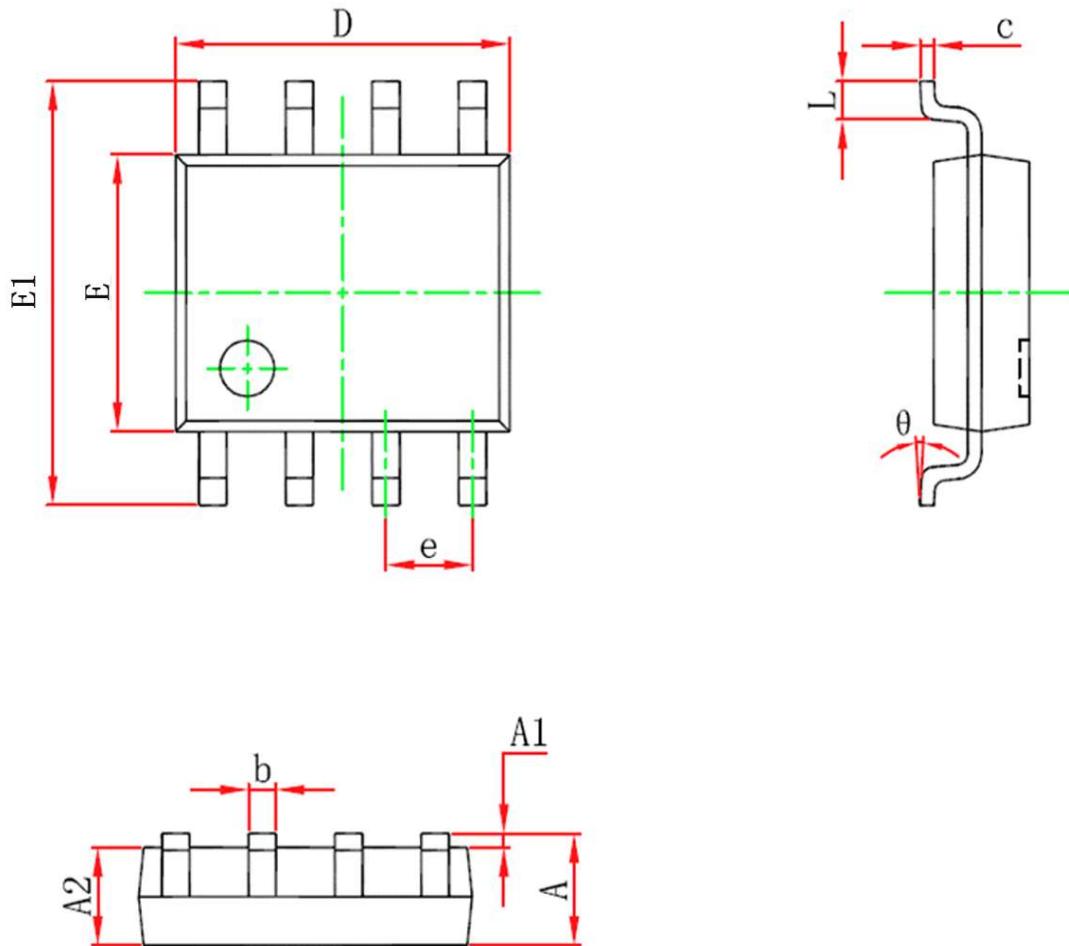


Fig6 Typical Capacitance Vs.Drain-Source Voltage  
 $V_{DS}$  , Drain-Source Voltage (V)

## SOP-8 Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	1.450	1.750	0.057	0.068
A1	0.100	0.250	0.003	0.009
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.012	0.020
c	0.170	0.250	0.006	0.009
D	4.700	5.100	0.185	0.200
e	1.270(BSC)		0.050(BSC)	
E	3.800	4.000	0.149	0.157
E1	5.800	6.200	0.228	0.244
L	0.400	1.270	0.015	0.050
θ	0°	8°	0°	8°